



The first beam test of a GEM-readout TPC module with a large aperture GEM-like gating device

Yumi Aoki(SOKENDAI/KEK)

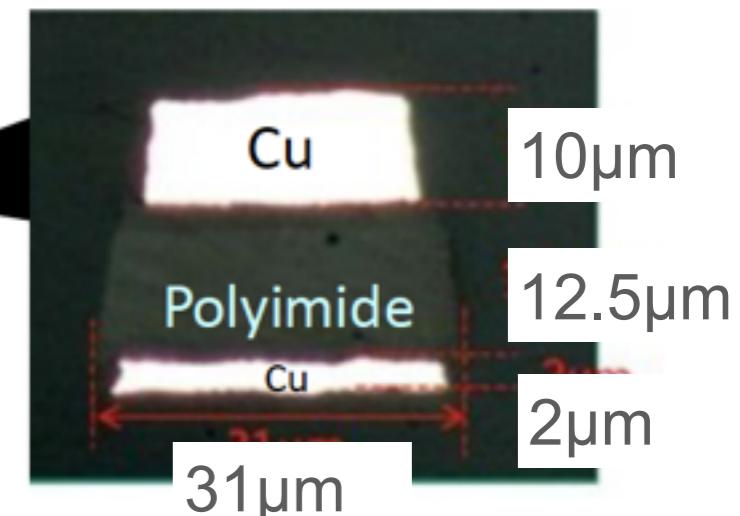
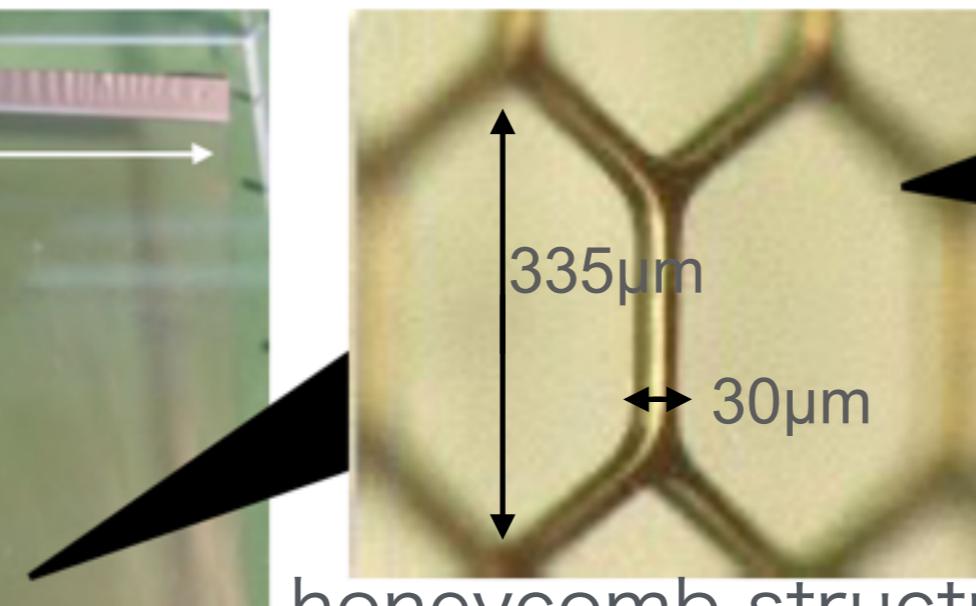
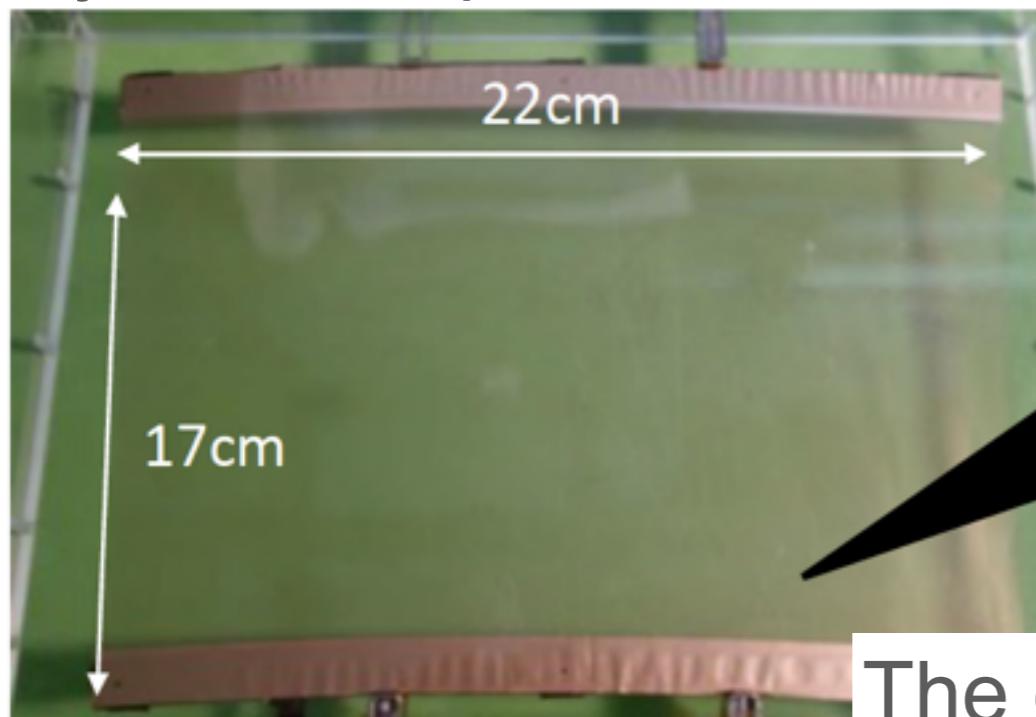
Yumi Aoki(SOKENDAI), Keisuke Fujii(KEK), Ryo Yonamine(KEK), Makoto Kobayashi(KEK), Takeshi Matsuda(KEK), Tomohisa Ogawa, Shinya Narita(Iwate Univ.), Kentaro Negishi(Iwate Univ.), Aiko Shoji(Iwate Univ.), Akira Sugiyama(Saga Univ.), Takahiro Fusayasu(Saga Univ.), Tohru Takahashi(Hiroshima Univ.), Takashi Watanabe(Kogakuin Univ.), Yukihiro Kato(Kinki Univ.), Katsumasa Ikematsu(IMRAM Tohoku Univ.), Ronald Dean Settles(MPI Munich), Junping Tian(Tokyo Univ.), Daisuke Arai(Fujikura Ltd.), Paul Colas(Saclay), Serguei Ganjour(Saclay), Ralf Diener(DESY), Oliver Schäfer(DESY), Shin-ichi Kawada(DESY), Felix Müller(DESY), Leif Jönsson(Lund Univ.), Ulf Mjörnmark(Lund Univ.), Huirong Qi(IHEP), Daisuke Kihara(Siegen Univ.), and the LCTPC collaboration

A large aperture GEM-like gating device



GEM as a gate = a large aperture GEM-like gating device
(gating GEM)

The joint development with FUJIKURA



honeycomb structure

The optical transparency = 82 % 25 μm thick

Though gating GEM stop positive ions, should not stop electron too. → Electron transmission rate is important

To achieve 100 μm of position resolution,
We need 80% electron transmission rate

Electron transmission rate in the attainable high electromagnetic field ÷ Optical transparency

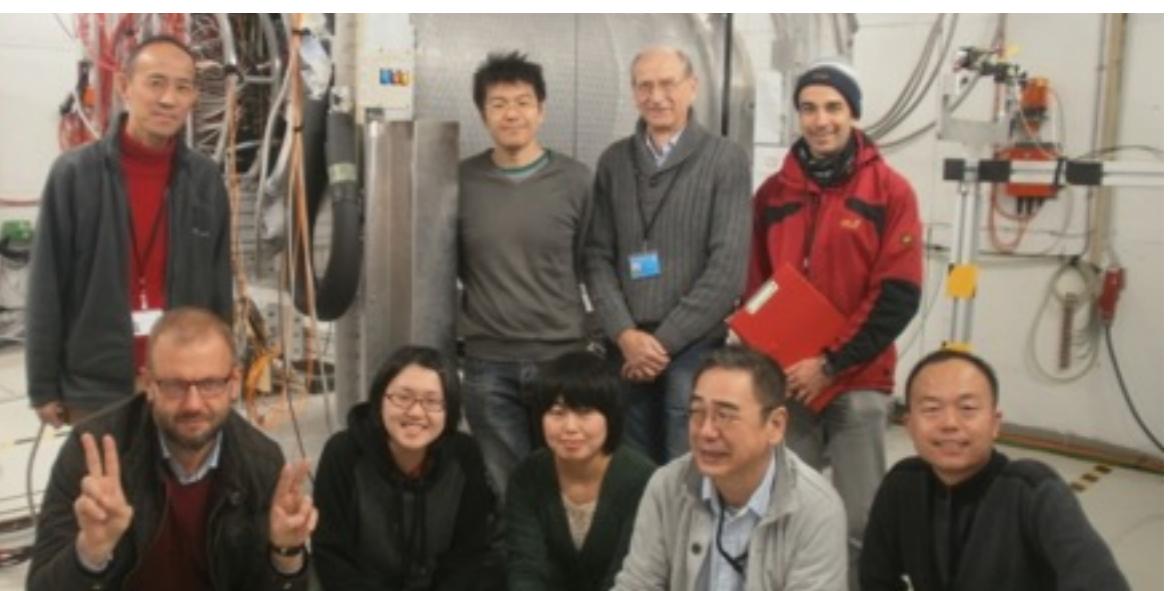
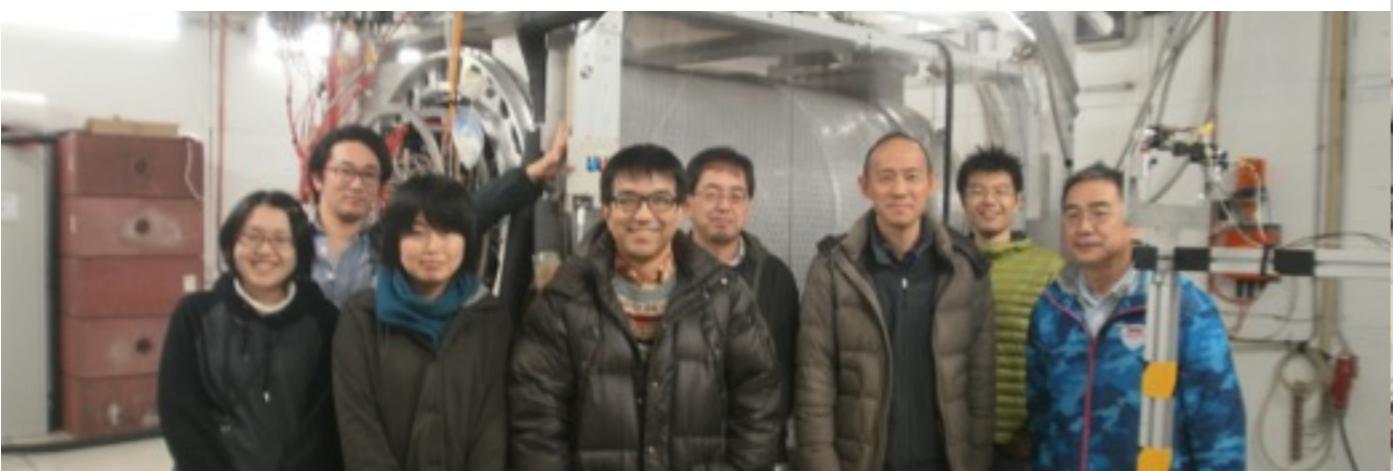
→ We checked by beam test

Beam test



2016.10.31~11.13 (beam time)
@DESY TPC large prototype
The first beam test
of a GEM-readout TPC module
with a gating GEM

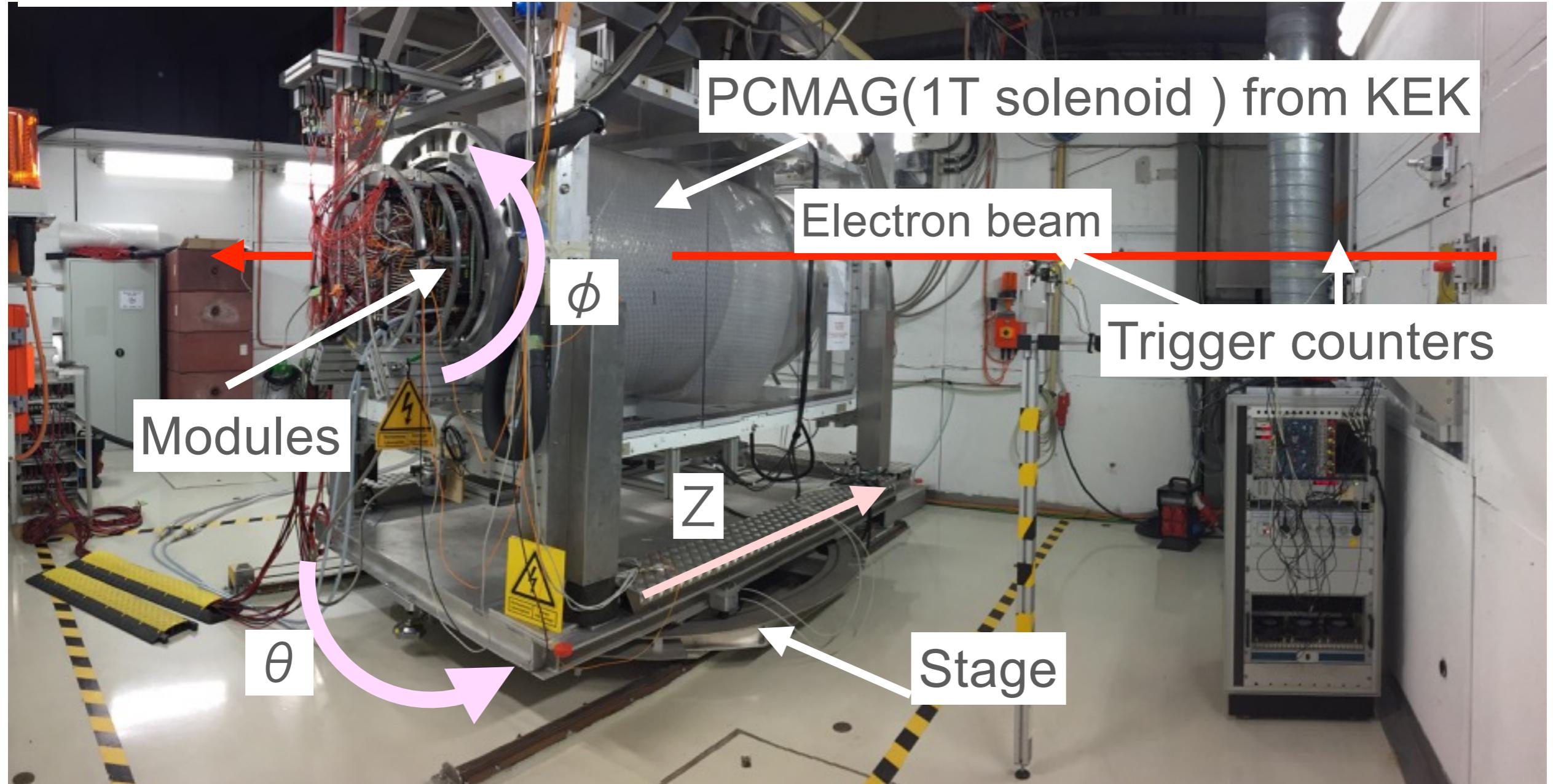
15 participants from Japan,
France, Germany, China



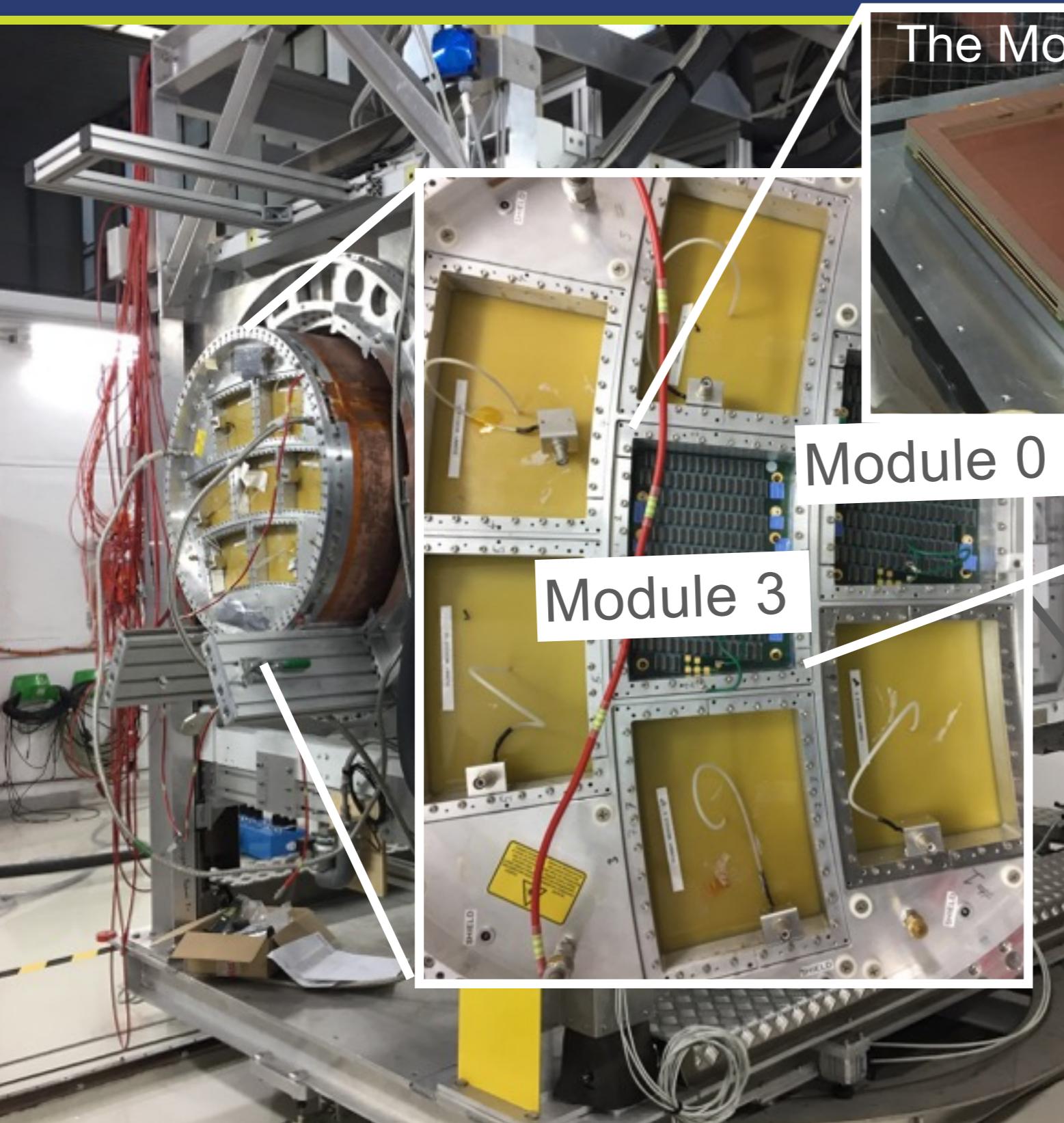
Setup



TPC large prototype

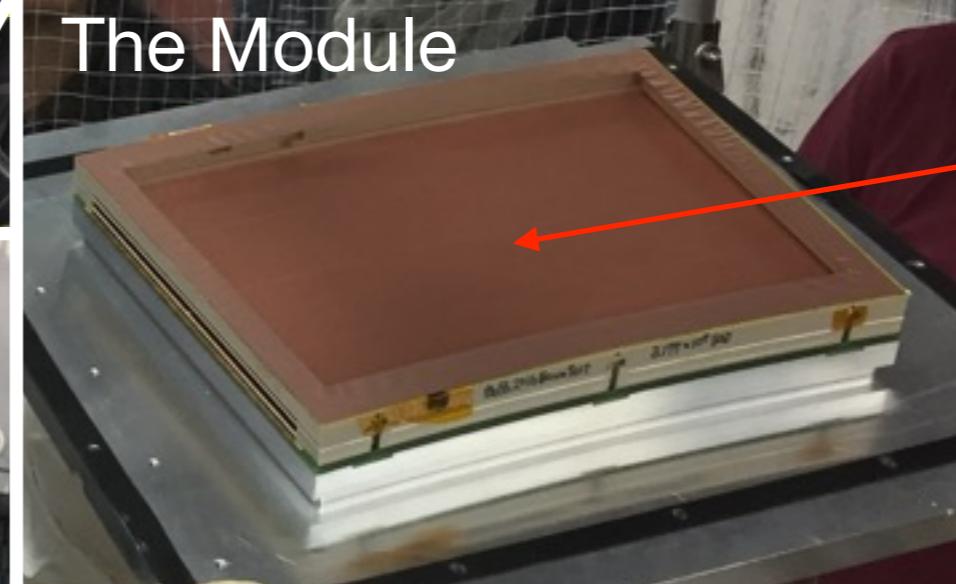


Module with Gating GEM



Module 0

Module 3



Gating GEM

Gating GEM
(A field shaper when without gate)

Amplification GEM
100 μm thickness

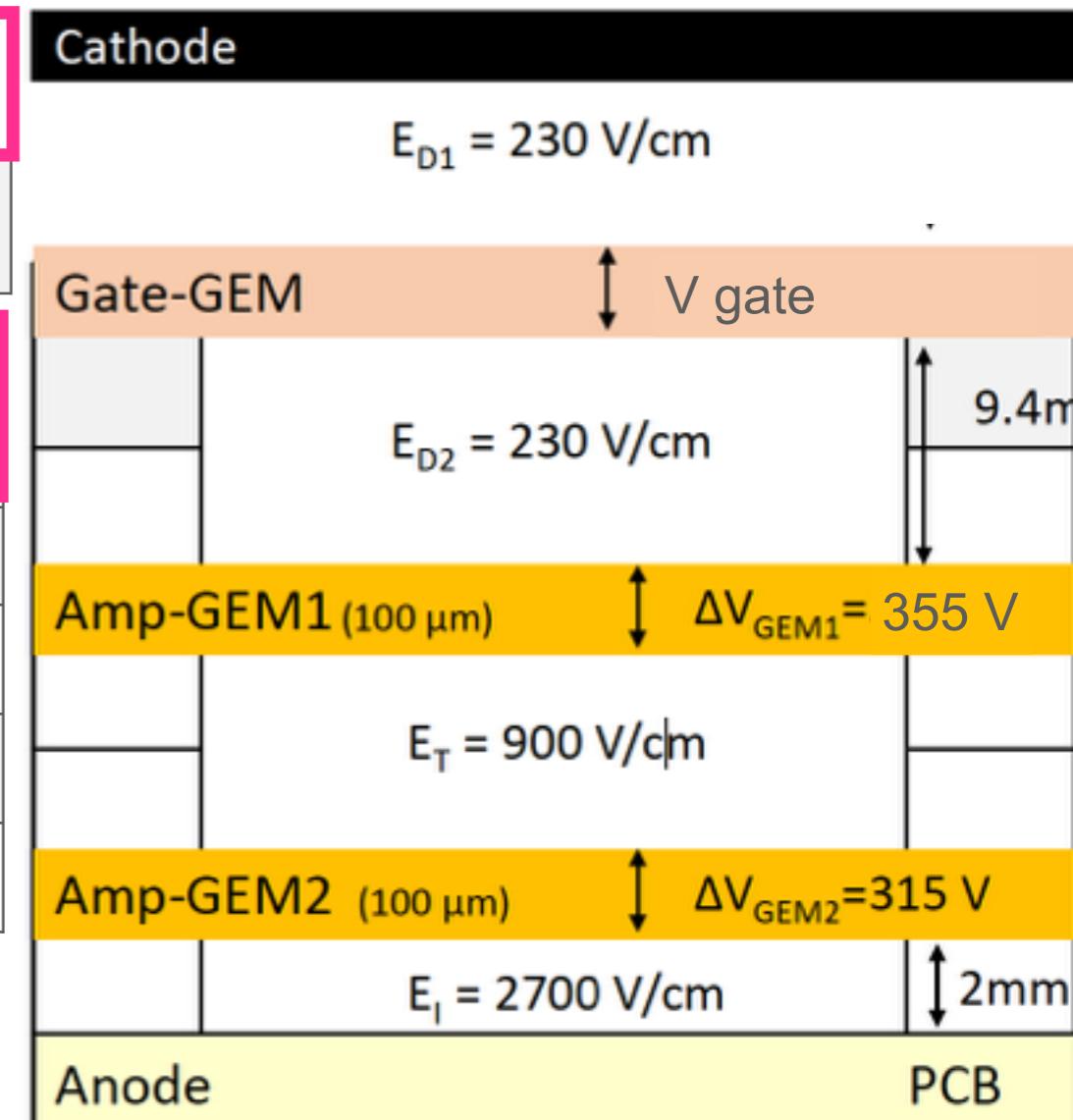
Pad plane(anode)
(Gathering 5152 pads)

実験条件



Module 3	With Gating GEM	Without Gating GEM
Module 0	Without Gating GEM	Without Gating GEM
Z[cm] (Drift length)	1.25,2.5,5,7.5,10,12.5,15,20 25,30,35,40,45,50,55	
ϕ [degree]	0,10,20	
θ [degree]	-20,-10,0,10,20	
V_{gate} [V]	-3.5,0,3.5	
B[T]	0,1	

Analyze condition of



Beam: 5 GeV electron

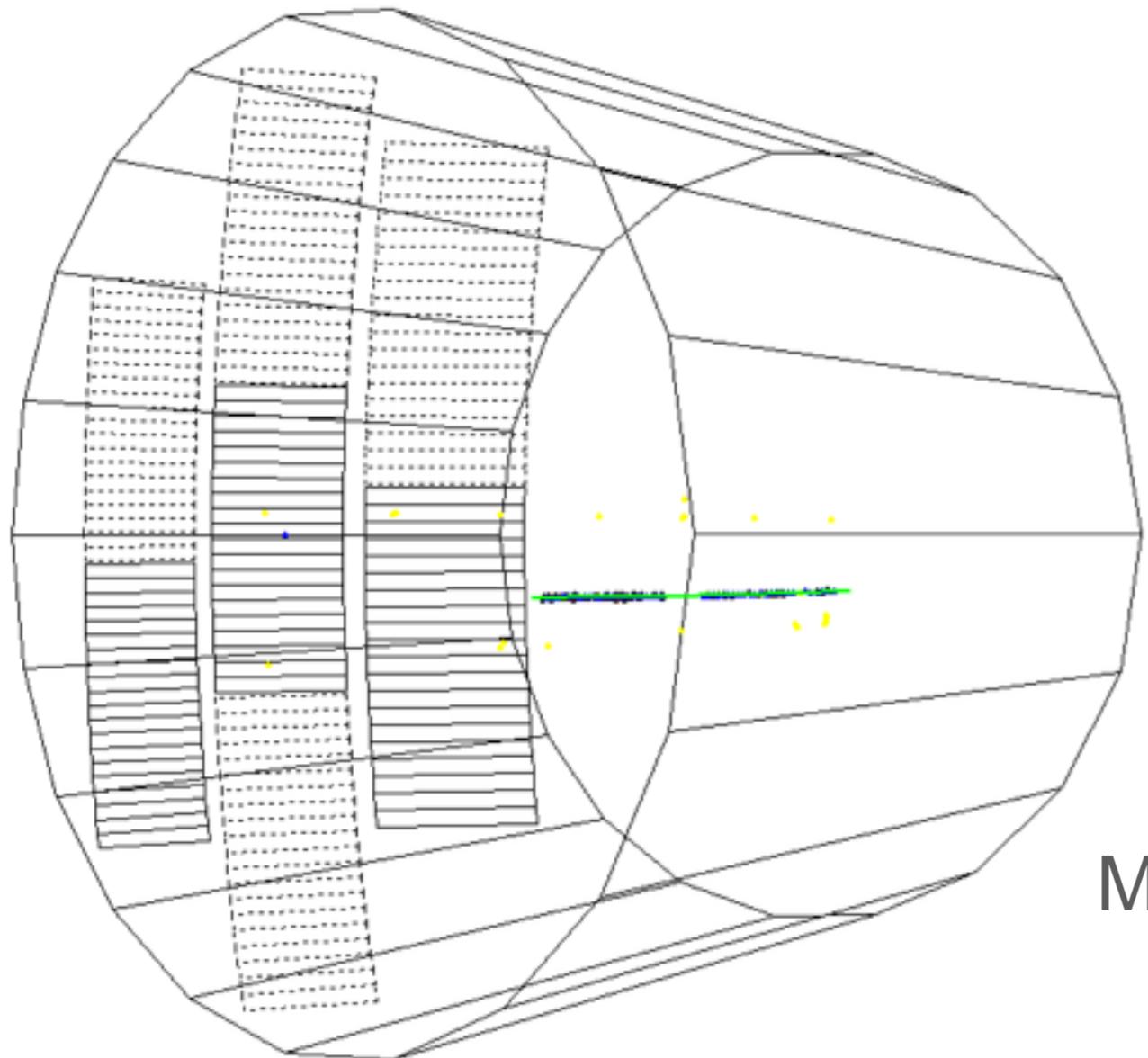
Gas:T2K gas (Ar : CF₄ : Iso-C₄H₁₀ = 95 : 3 : 2 [%])

Analytics framework:MarlinTPC (Analysis 20000 event/1 run)

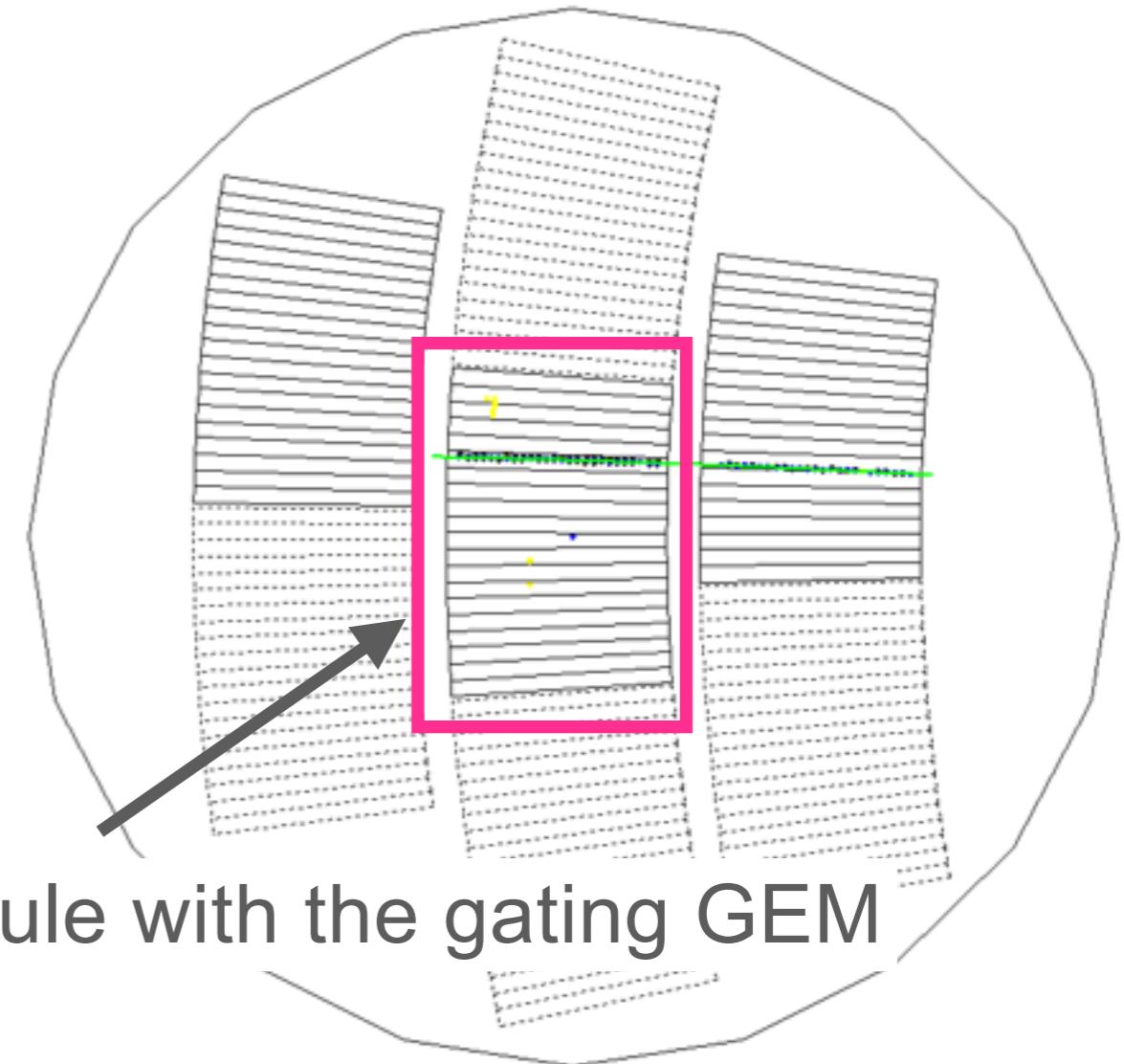
Typical event



From side

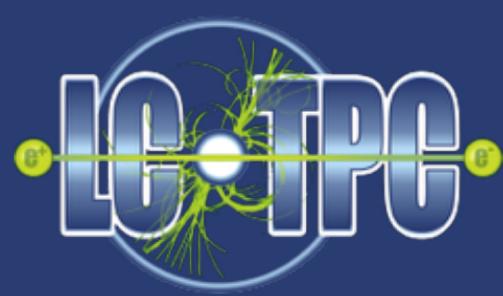


From top

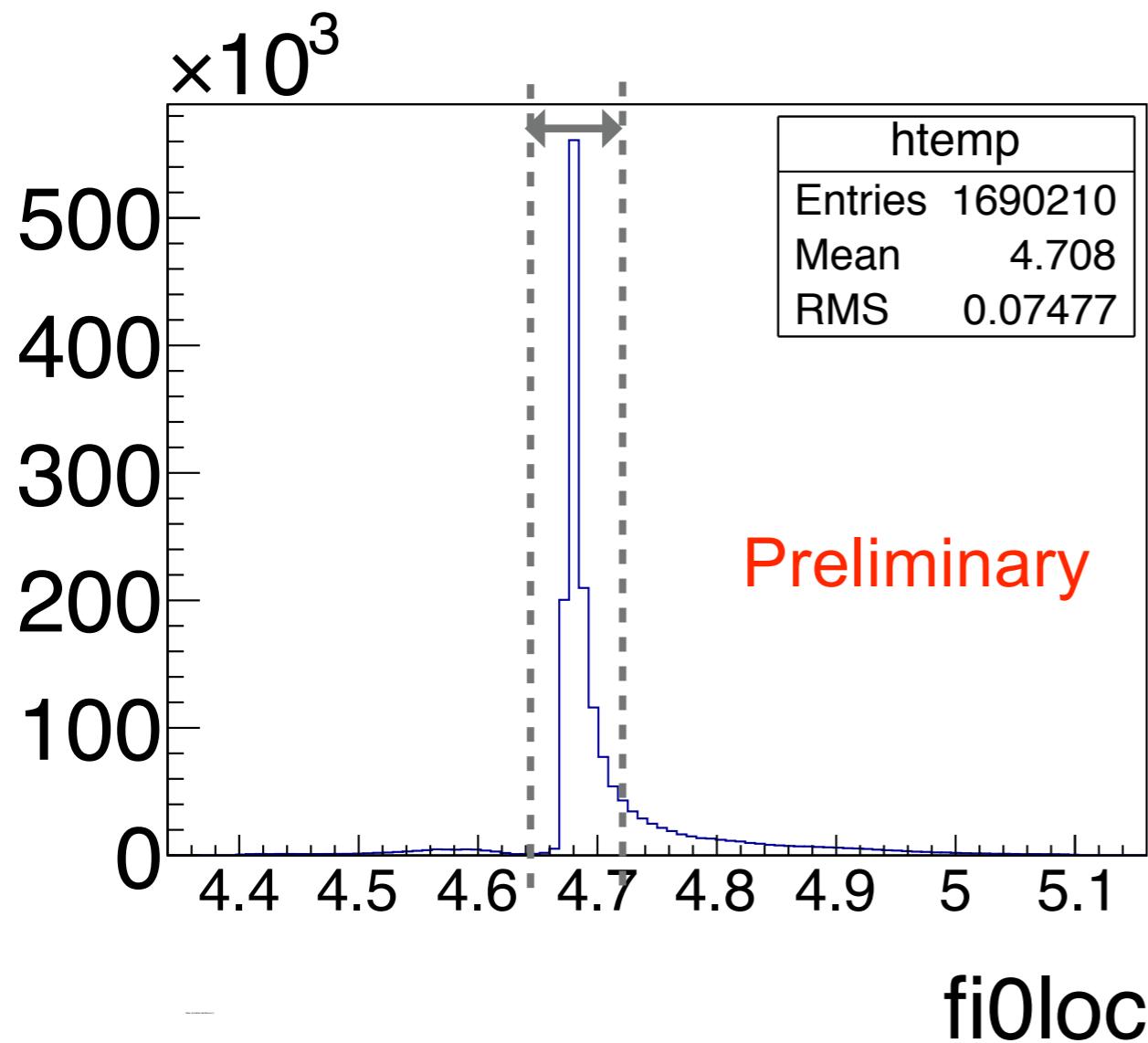


An electron goes through our module with our gating device far from edge.

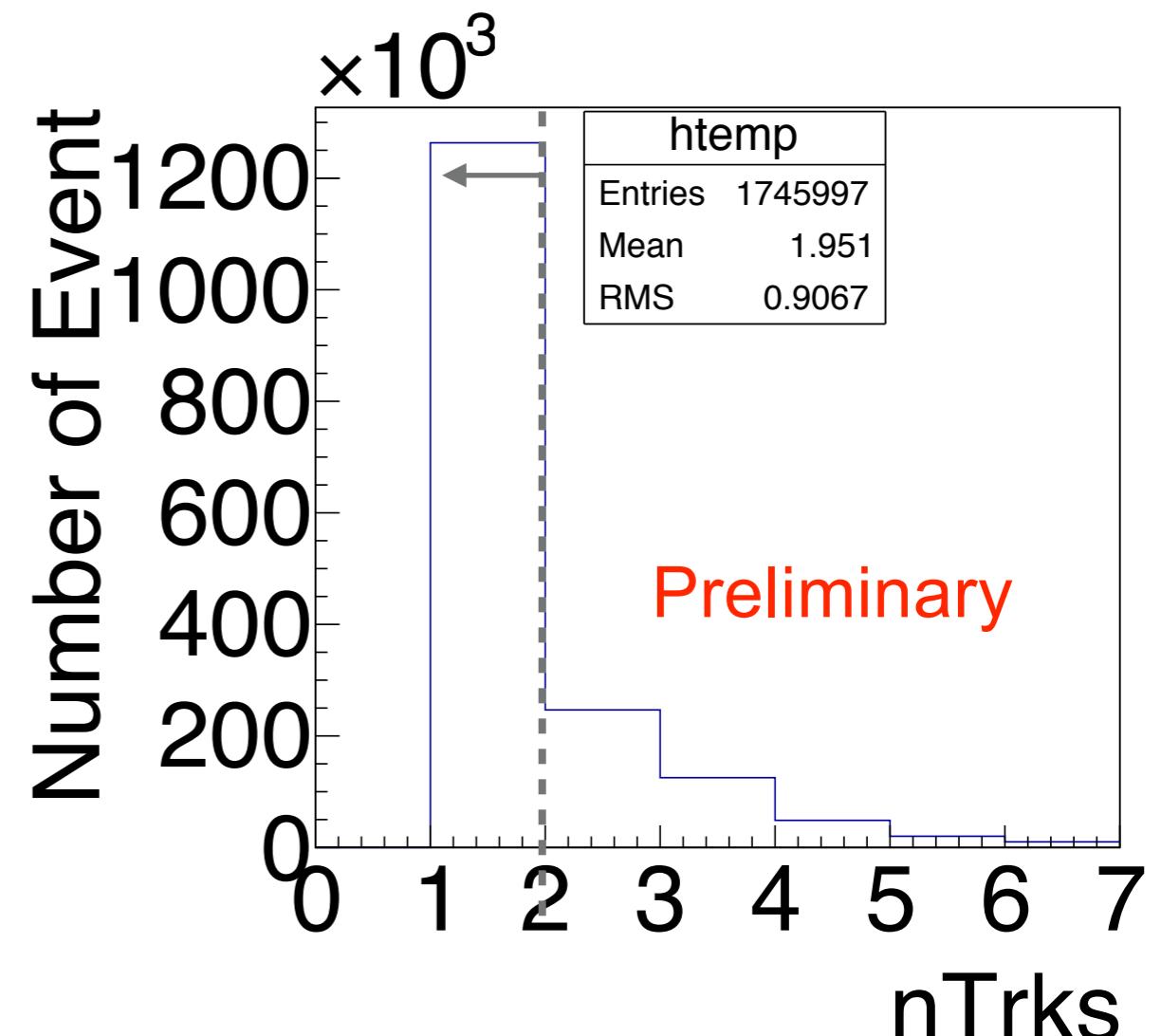
Event Selection



Track angle cut[rad]
 $4.64 < \phi_0 < 4.72$



of tracks per event
 $nTrks = 1$

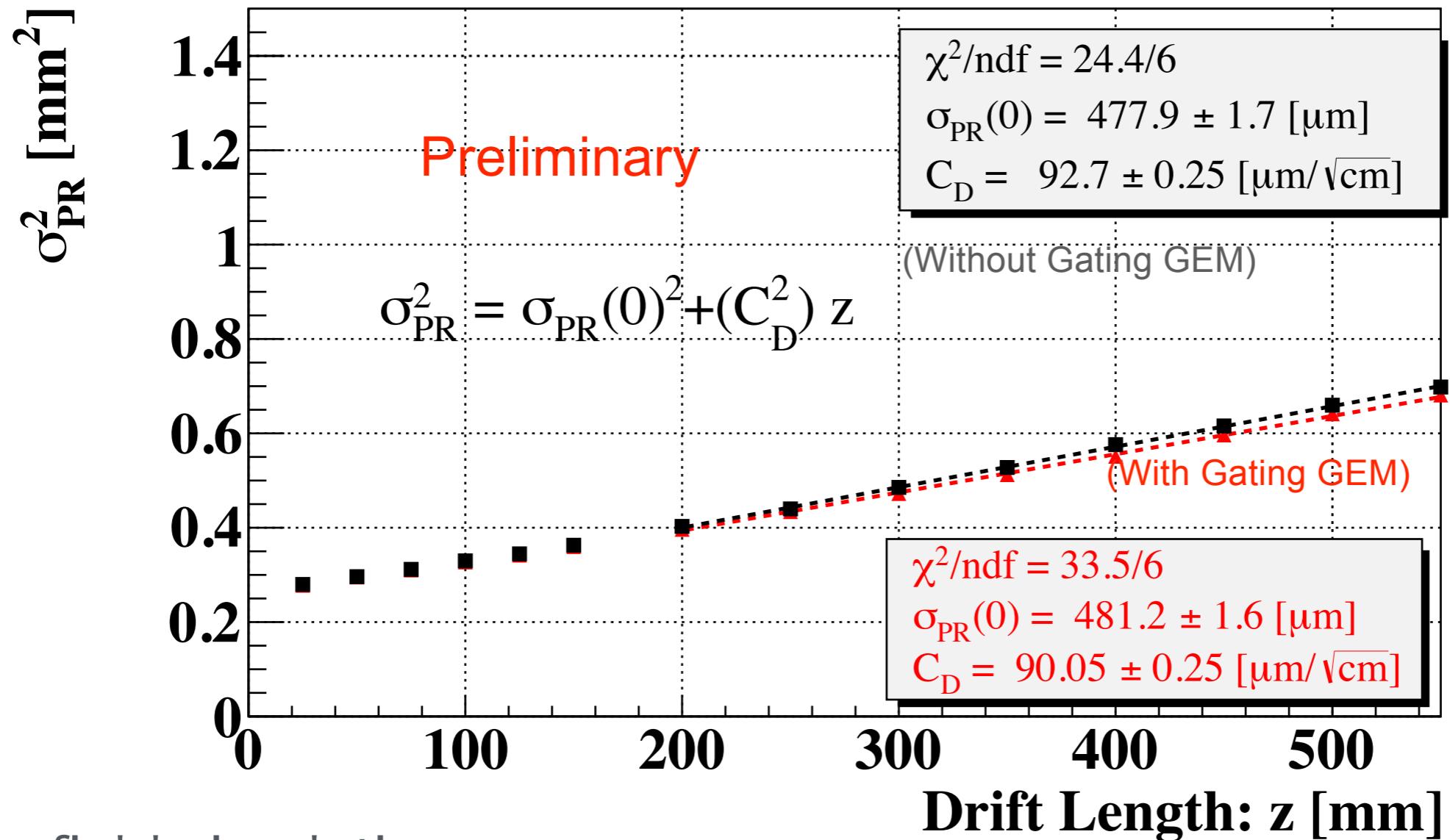


I applied a track angle cut to exclude angled tracks and a cut on $nTrks$ to eliminate events with multiple tracks caused by electromagnetic shower in the upstream.

Pad response



Pad Response (Module3 Row16)



Garfield simulation

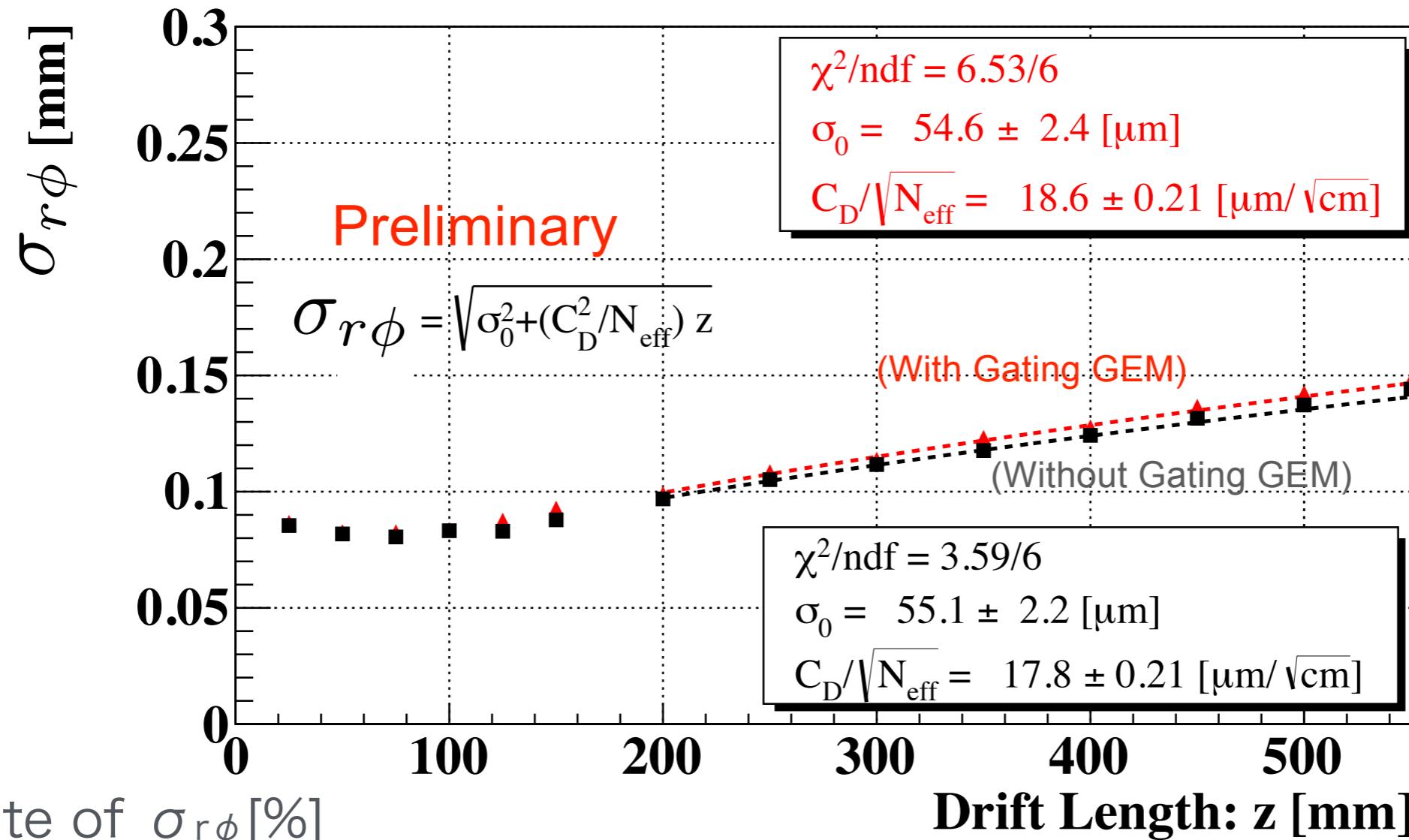
C_d (condition with gating GEM) $94.0 \mu\text{m}/\sqrt{\text{cm}} \pm 0.2\%$

C_d (condition without gating GEM) $94.2 \mu\text{m}/\sqrt{\text{cm}} \pm 0.3\%$

GM resolution ($r\phi$)



GM Resolution (Module3 Row16)



	2.5	5	7.5	10	12.5	15	20	25	30	35	40	45	50	55
Ratio	101.7	101.2	102.9	100.7	105.8	105.8	102.4	103.3	102.1	104.8	103.0	104.0	103.8	102.7
/%	± 0.1	± 0.2												

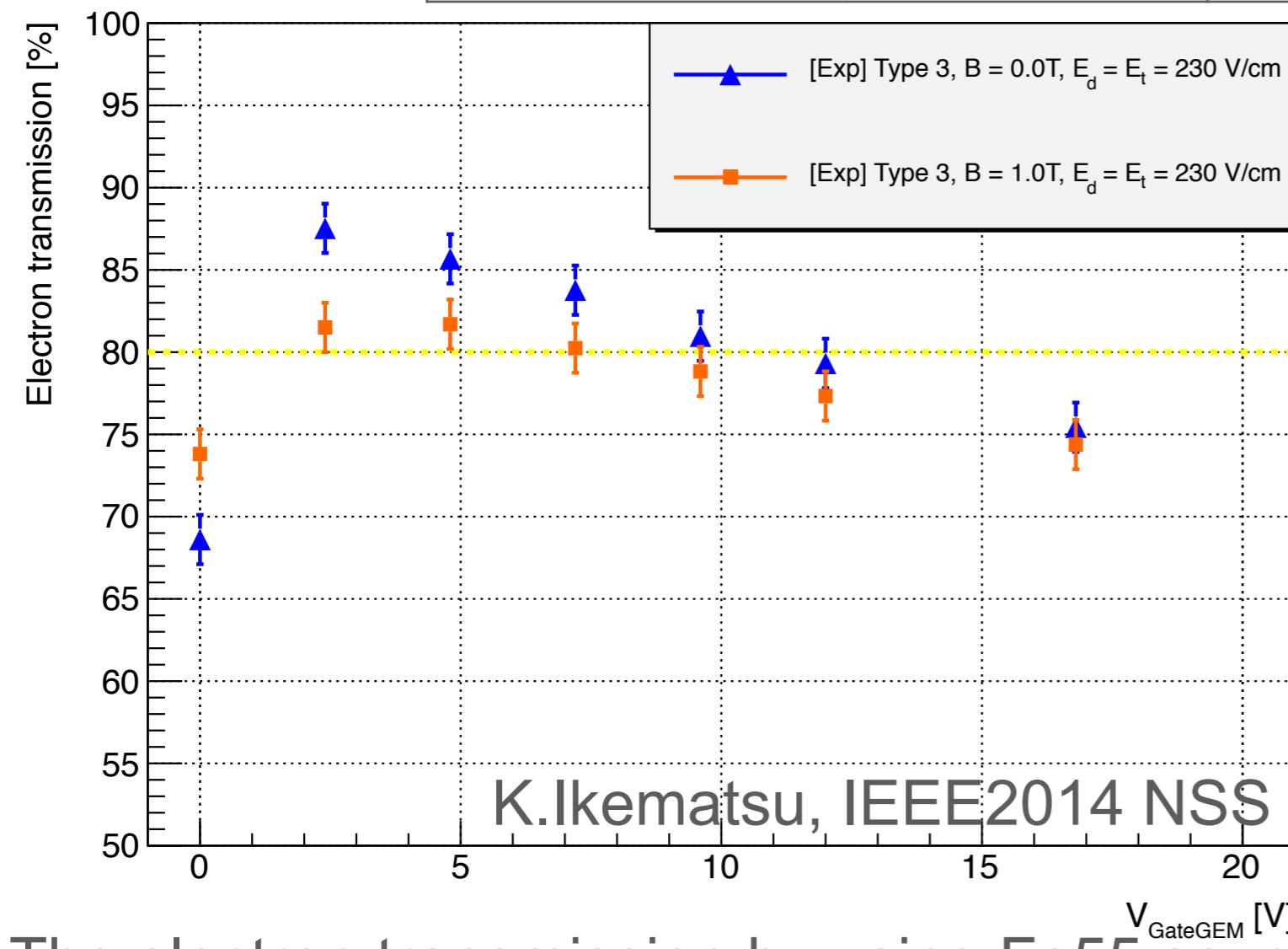
Expected rate : 110 %

Preliminary(Stat. only)

Electron transmission rate



Used Cd values [$\mu\text{m}/\sqrt{\text{cm}}$]	$N_{\text{eff}}(\text{With gate})$	$N_{\text{eff}}(\text{Without gate})$	rate[%]
measurement	23.4 ± 0.6	27.1 ± 0.7	86.4 ± 3.0
Simulation	26.7 ± 0.7	30.0 ± 0.9	89.1 ± 3.3



The electron transmission rate estimated by Neff is more than 80%

Neff used the measurement Cd value is more nearer the measurement result of the small prototype $\approx 82\%$.

The electron transmission by using Fe55 source 10cm×10cm prototype(1 T)

Summary



We succeeded the first beam test of a GEM-readout TPC module with a large aperture GEM-like gating device



The electron transmission by using the measurement is $86.4 \pm 3.0\%$

We achieved the electron transmission rate benchmark.

The problem

The difference of Cd with/without gating GEM

We pursuit of causes by comparison of the result of module 0 which measured in same time.